

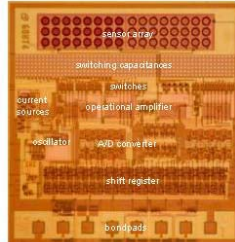
Reliability of MOEMS in harsh conditions

Objectives

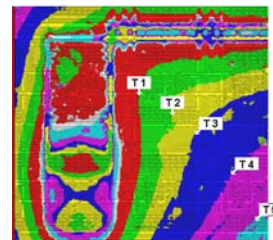
- MOEMS working in harsh conditions arising from the environment (space, corrosive gas, high pressure, high temperature $T > 150^{\circ}\text{C}$, liquids, shocks,...) or from their operation (high current density, large deflections, high voltages,...) are severely prone to reliability issues.
- As MOEMS applications at “harsh” environment are steadily increasing it’s essential to focus the expertise of the Patent-DfMM partners in a first step in order to collect information on reliability issues and on very application specific test approaches existing at each lab.
- In the current project (phase I), the team is working on following activities: hardware setup (BUTE, CSL), design of test structures (IEF, IMS), packaging issues (IMS).

Partners involved and roles

- IEF – Reliability of high current density actuators
- IMS – Coordinator, Reliability of high temperature devices
- BUTE – Thermal measurements on high temperature and high current density MEMS
- IMT – Reliability in salt mist and damp heat
- CSL – Reliability in space
- IXL – Reliability of high voltage MEMS
- IZMM – Reliability in liquids



Test devices: micro pumps (source: IZMM), HT-EEPROM (source: IMS), integrated surface micromachined pressure sensor on SOI (source: IMS)



Liquid Crystal Thermal Mapping (difference between adjacent isotherms is 0.16°C) (source: BUTE)



Cracks in single crystal silicon support beams caused by vibrations induced by a launch simulation (source: CSL)

Summary of results

- A final report of more than 70 pages has been compiled containing information obtained from experiences at the partners labs, from literature research and from experiments like e.g.:
- Electromigration in copper microcoils as parts of electromagnetic actuators,
- Investigation of assembly materials for integrated MEMS for operation at temperatures up to 300°C .

Offer to industry

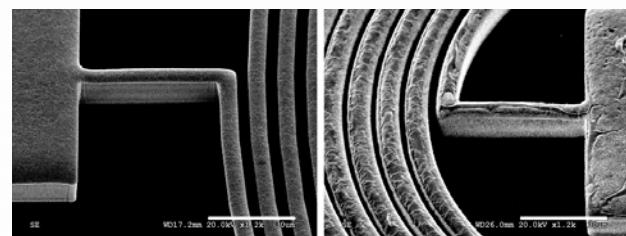
- Advisory service for design, packaging and test of MOEMS in harsh conditions.
- Development of SOI-devices for high temperature applications.
- Conduction of tests under harsh conditions.

Contact Dr Hoc Khiem Trieu (trieu@ims.fhg.de)

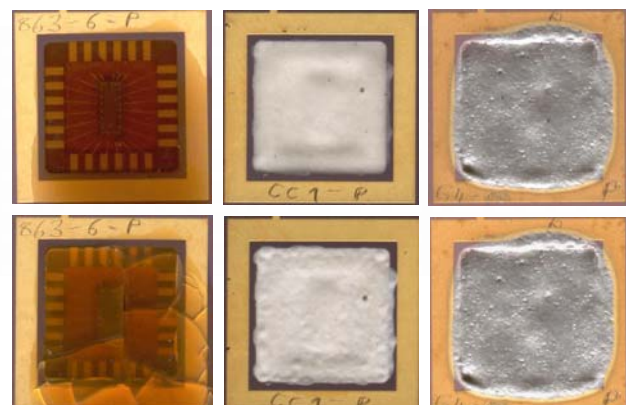
Project status

Phase 1 completed, April 2005

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Comparison between two identical on-wafer Cu-microcoils: an original one (left) and one after high current density stress (right) (source: IEF)



Investigation of appropriate material for die bonding and glob top (samples under test after 100 and 300 thermal cycles) (source: IMS)